

Supporting Information

Asymmetric Non-fullerene Small Molecule Acceptor with Unidirectional Non-fused π -bridge and Extended Terminal Group for High-efficiency Organic Solar Cells

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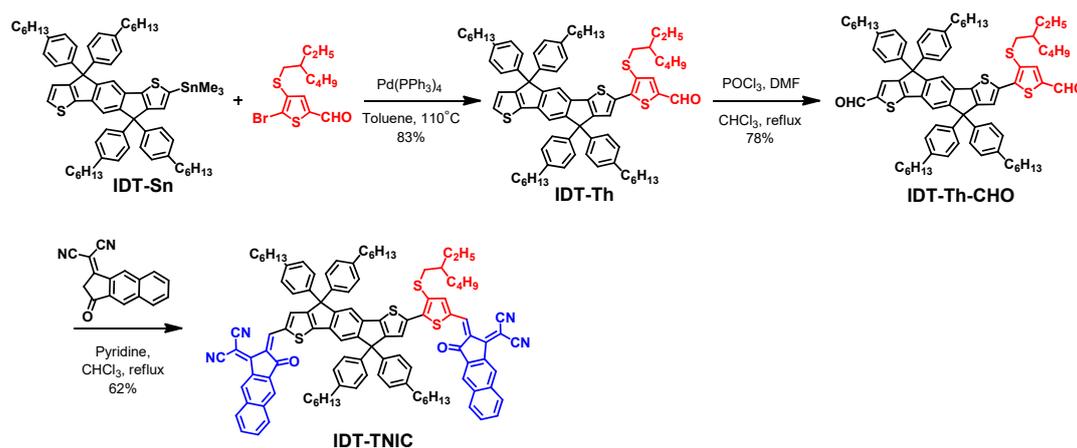
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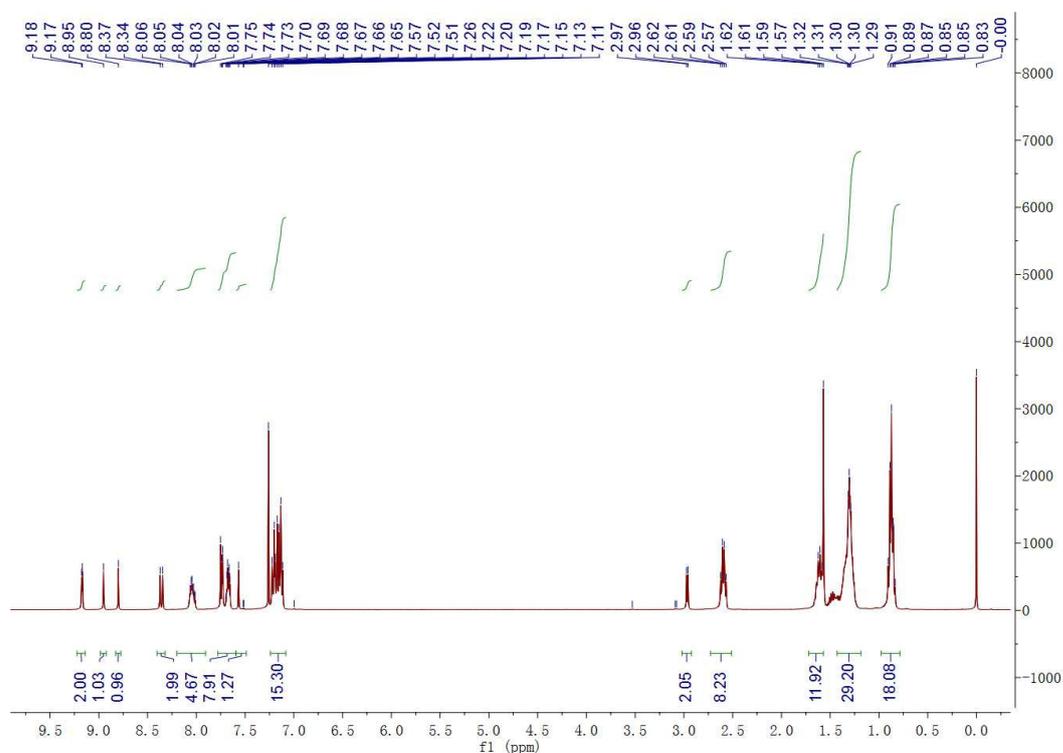
Experimental section

Materials.

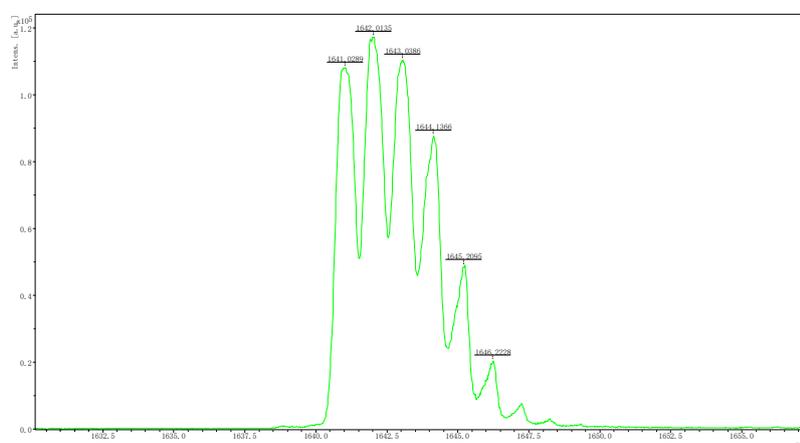
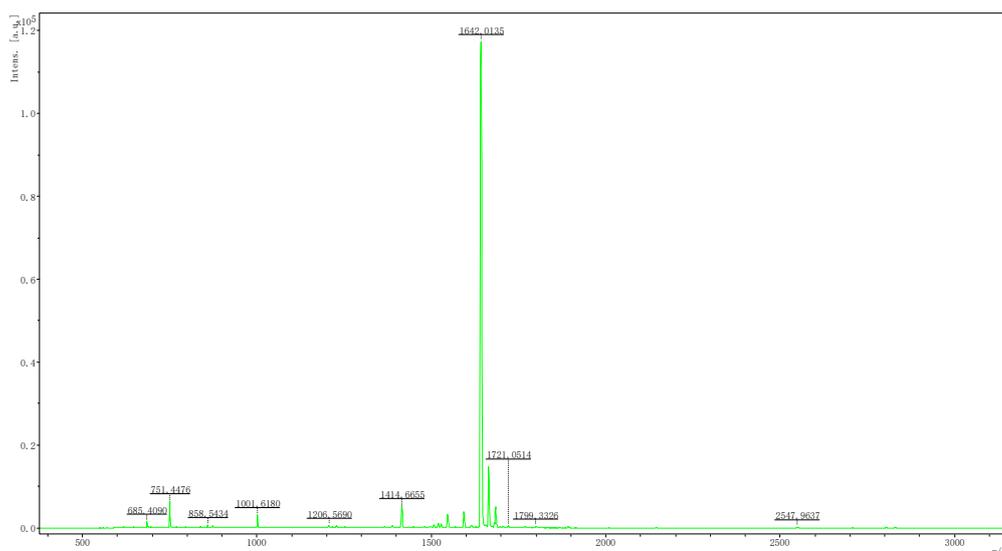
All chemicals and solvents were reagent grades and purchased from Alfa Aesar, J&K, and Aldrich, respectively. IDT-Sn [1], IDT-Th [2] and IDT-Th-CHO [2], was synthesized according to reported before. The molecular structure and synthetic route of IDT-TNIC is shown in Scheme S1, the detailed as follows:



Scheme S1. The synthetic route and molecular structure of IDT-TNIC.



^1H NMR of IDT-TNIC in CDCl_3 .



MALDI-TOF of IDT-TNIC

Instruments and measurements

^1H NMR and ^{13}C NMR were measured in CDCl_3 on Bruker AV 400 MHz FT-NMR spectrometer. MALDI-TOF was measured on ultrafleXtreme™ Mass spectrometer from Bruker Daltonics. UV-Vis absorption spectra were measured by an Agilent Carry-5000 UV-Vis spectrophotometer. The solubility of PBSF-A12, PBSF-D12 and PBDB-T-SF in different solution were calculated according to the method reported in the literature. [4] Electrochemical cyclic voltammetry (CV) was performed on a Zahner Zennium IM6 electrochemical workstation with a three-electrode system in 0.1 mol L^{-1} Bu_4NPF_6 acetonitrile solutions at a scan rate of 50 mV s^{-1} . Elemental analysis was carried out on a flash EA1112 analyzer. The molecular weight of the polymer was measured by the GPC method with polystyrene as the standard and 1,2,4-trichlorobenzene as the solvent at $160 \text{ }^\circ\text{C}$ using Agilent Technologies

PL-GPC220. Thermogravimetric analysis (TGA) was measured on Discovery TGA from TA Instruments Inc. at a heating rate of $10\text{ }^{\circ}\text{C min}^{-1}$ under a nitrogen atmosphere. Differential scanning calorimetry (DSC) was performed on a TA DSC Q-200 at a scan rate of $10\text{ }^{\circ}\text{C min}^{-1}$ under nitrogen atmosphere. X-Ray Diffraction (XRD) was performed on a X'Pert-ProMRD. Photoluminescence (PL) spectra were performed on an Edinburgh Instrument FLS 980. The atomic force microscopy (AFM) measurement was carried out on a Dimension 3100 (Veeco) Atomic Force Microscope in the tapping mode. Transmission electron microscopy (TEM) was performed on a Tecnai G2 F20 S-TWIN instrument at 200 kV accelerating voltage. The GWAXS measurements were performed at beamline 7.3.3 at the Advanced Light Source (ALS). The current-voltage (J - V) characteristics of the devices were measured on a Keithley 2450 Source Measure Unit. The power conversion efficiency of the OSCs was measured under an illumination of AM 1.5G (100 mW cm^{-2}) using a SS-F5-3A (Enli Technology Co. Ltd.) solar simulator (AAA grade, 50 mm x 50 mm photobeam size). The EQE was measured by Solar Cell Spectral Response Measurement System QE-R3011 (Enli Technology Co. Ltd.). The light intensity at each wavelength was calibrated with a standard single-crystal Si photovoltaic cell.

Mobility measurement

The mobility was measured by the space charge limited current (SCLC) method by a hole-only device with a structure of ITO/PEDOT:PSS/PBDB-T or PBDB-T:IDT-TNIC/MnO₃(10 nm)/Al(100 nm) or an electron-only device with a structure of ITO/ZnO-NP/PBDB-T:IDT-TNIC or IDT-TNIC /PFN-Br/Al(100 nm) and estimated through the Mott-Gurney equation. For the hole-only devices, SCLC is described by $J \cong (9/8) \varepsilon\varepsilon_0\mu_0V^2\exp(0.89\sqrt{V/E_0L})/L^3$, Where ε is the dielectric constant of PM6:Acceptors, ε_0 is the permittivity of the vacuum, μ_0 is the zero-field mobility, E_0 is the characteristic field, J is the current density, L is the thickness of the films, $V = V_{\text{appl}} - V_{\text{bi}}$, V_{appl} is the applied potential, and V_{bi} is the built-in potential which results from the difference in the work function of the anode and the cathode (in this device structure, $V_{\text{bi}} = 0.2\text{ V}$). For the electron-only devices, SCLC is

described by $J = \frac{8}{9} \epsilon_r \epsilon_0 \mu_c \frac{V^2}{L^3}$, where J is the current density, ϵ_r is the dielectric constant of IDT-TNIC, ϵ_0 is the permittivity of the vacuum, L is the thickness of the blend film, $V = V_{\text{appl}} - V_{\text{bi}}$, V_{appl} is the applied potential, and V_{bi} is the built-in potential which results from the difference in the work function of the anode and the cathode (in this device structure, $V_{\text{bi}} = 0$ V).

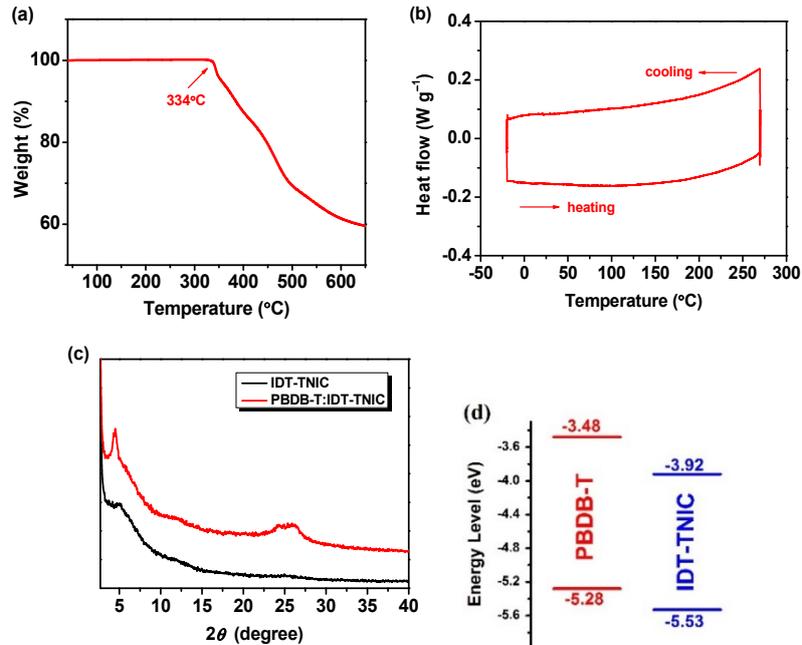
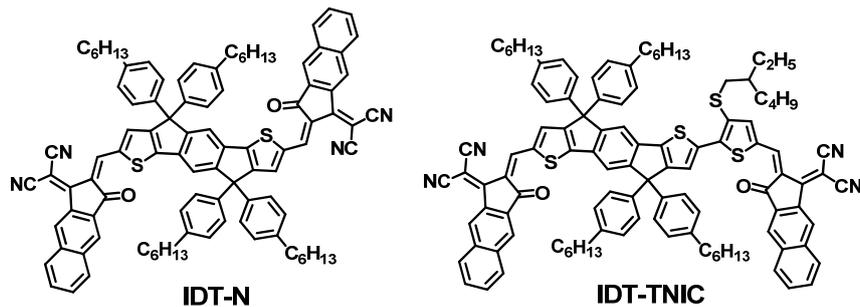


Figure S1. (a) TGA and (b) DSC of IDT-TNIC, (c) XRD of IDT-TNIC pure film and PBDB-T:IDT-TNIC blend film, (d) Energy level diagram of PBDB-T and IDT-TNIC.

Table S1. Optical and electrochemical properties of IDT-TNIC.

Material	UV-vis in solution		UV-vis in solid film			CV			Dipole moment (Debye) ^{b)}
	λ_{max} (nm)	λ_{edge} (nm)	λ_{max} (nm)	λ_{edge} (nm)	$E_{\text{g}}^{\text{opt}}$ (eV)	HOMO (eV)	LUMO (eV)	E_{g}^{cv} (eV)	
IDT-TNIC	727	809	755	862	1.44	-5.53	-3.92	1.61	4.30
IDT-N ^{a)}	687	725	727	784	1.58	-5.74	-4.08	1.66	0.00 [3]

^{a)} Reported in literature. ^{b)} Obtained from gaussian theoretical simulation



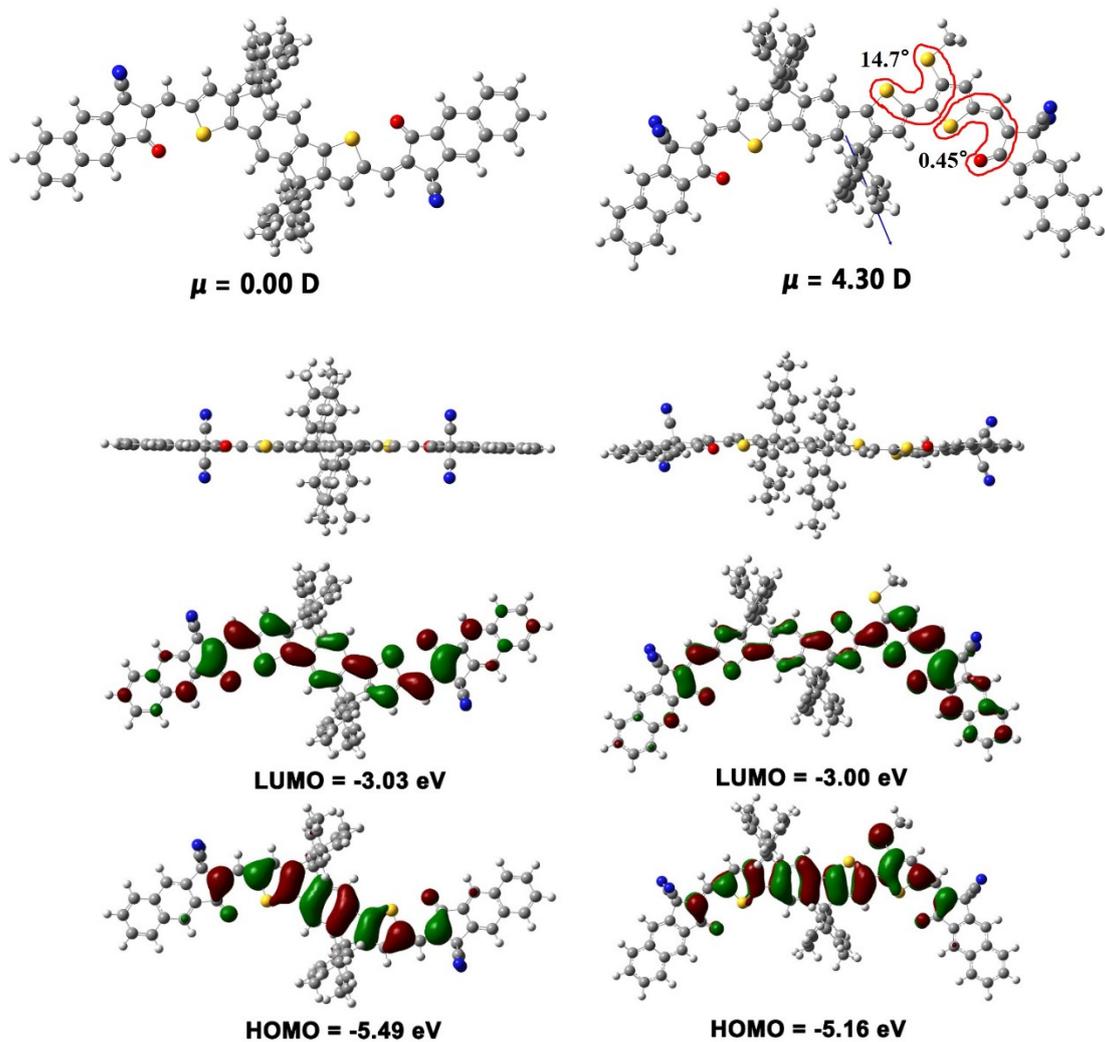


Figure S2. Chemical structures of IDT-N (left) and IDT-TNIC (right), and the corresponding molecular conformations and the electron cloud distribution of frontier molecular orbital via DFT-based theoretical calculations at the B3LYP/6-31G(d,p) level. (All side chains are simplified as the methyl groups.)

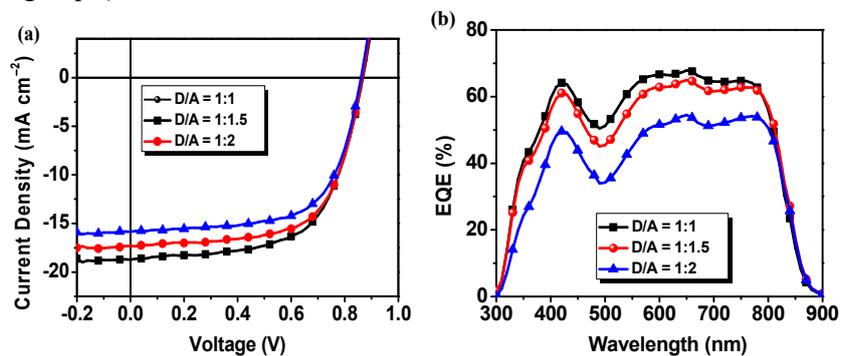


Figure S3. (a) J - V plots of PBDT-T:IDT-TNIC-based OSCs with different D/A under the illumination of AM 1.5G, 100 mW cm^{-2} , (b) The corresponding EQE curves of the OSCs.

Table S2. Photovoltaic parameters of PBDT-T:IDT-TNIC-based OSCs with different D/A under the illumination of AM 1.5G, 100 mW cm^{-2} .

PBDB-T:IDT-TNIC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	Cal. J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
1:1	0.868	18.73	18.10	62.5	10.19
1:1.5	0.865	17.32	17.30	64.8	9.72
1:2	0.861	15.86	14.27	65.0	8.87

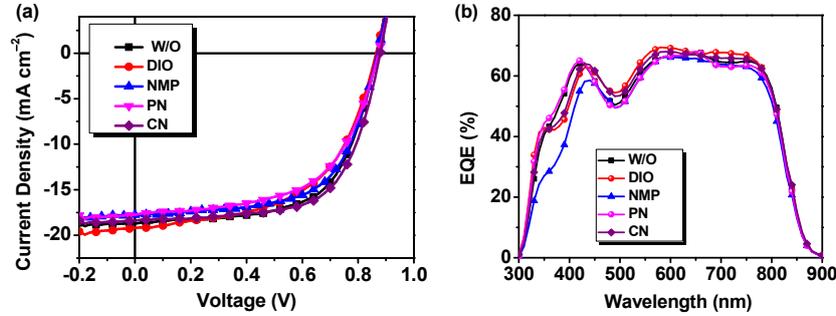


Figure S4. (a) J - V plots of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different additive under the illumination of AM 1.5G, 100 mW cm⁻², (b) The corresponding EQE curves of the OSCs.

Table S3. Photovoltaic parameters of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different additive under the illumination of AM 1.5G, 100 mW cm⁻².

PBDB-T:IDT-TNIC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	Cal. J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
W/O	0.863	18.84	18.10	61.6	10.19
DIO ^{a)}	0.865	19.20	18.54	55.2	9.32
NMP ^{b)}	0.869	17.76	17.32	62.3	9.79
PN ^{c)}	0.873	17.76	17.85	58.0	9.16
CN ^{d)}	0.879	18.41	18.34	64.6	10.46

^{a)} DIO is an abbreviation of 1,8-Diiodooctane. ^{b)} NMP is an abbreviation of N-Methylpyrrolidone. ^{c)} PN is an abbreviation of 1-Phenylnaphthalene. ^{d)} CN is an abbreviation of 1-Chloronaphthalene.

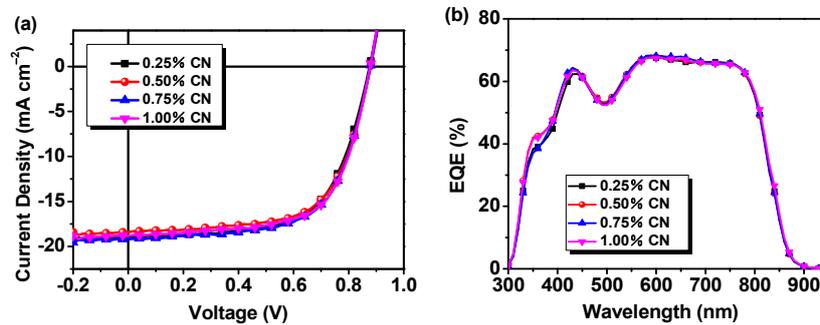


Figure S5. (a) J - V plots of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different CN contents under the illumination of AM 1.5G, 100 mW cm⁻², (b) The corresponding EQE curves of the OSCs.

Table S4. Photovoltaic parameters of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different CN contents under the illumination of AM 1.5G, 100 mW cm⁻².

PBDB-T:IDT-TNIC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	Cal. J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)
0.25% CN	0.876	18.98	18.25	63.6	10.58
0.50% CN	0.879	18.41	18.34	64.6	10.46
0.75% CN	0.879	19.20	18.37	64.2	10.84
1.00% CN	0.878	18.81	18.35	65.3	10.79

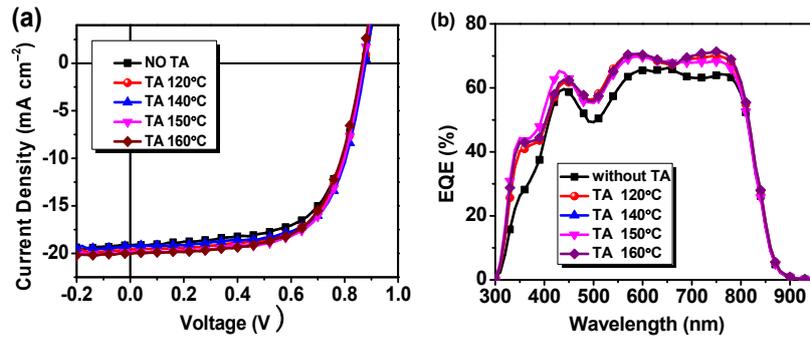


Figure S6. (a) J - V plots of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different TA temperature for 10 min, 0.75% CN as additive under the illumination of AM 1.5G, 100 mW cm⁻², (b) The corresponding EQE curves of the OSCs.

Table S5. Photovoltaic parameters of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different TA temperature under the illumination of AM 1.5G, 100 mW cm⁻².

PBDB-T:IDT-TNIC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	Cal. J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)	
NO TA	0.879	19.20	17.58	64.2	10.84	
0.75% CN, TA 10min	TA 120 °C	0.874	19.56	19.10	64.9	11.04
	TA 140 °C	0.878	19.21	18.77	66.9	11.21
TA 10min	TA 150 °C	0.875	19.23	18.93	66.3	11.22
	TA 160 °C	0.865	20.04	19.25	64.2	11.06

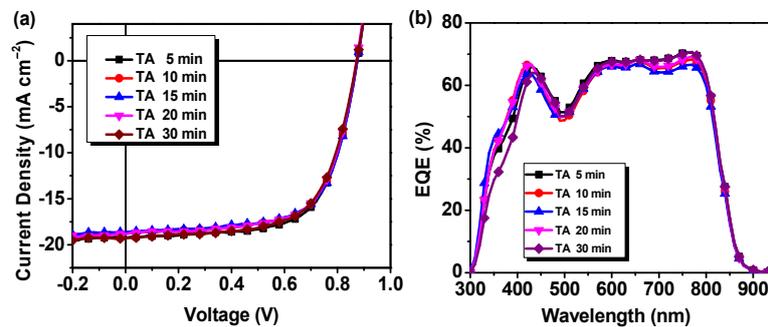


Figure S7. (a) J - V plots of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different TA time, 0.75% CN as additive and TA treatment at 150 °C under the illumination of AM 1.5G, 100 mW cm⁻², (b) The corresponding EQE curves of the OSCs.

Table S6. Photovoltaic parameters of PBDB-T:IDT-TNIC-based OSCs (1:1, w/w) with different TA time, 0.75% CN as additive and TA treatment at 150 °C under the illumination of AM 1.5G,

100 mW cm⁻².

PBDB-T:IDT-TNIC	V_{oc} (V)	J_{sc} (mA cm ⁻²)	Cal. J_{sc} (mA cm ⁻²)	FF (%)	PCE (%)	
0.75% CN TA 150 °C	5 min	0.871	19.85	18.86	65.9	11.32
	10 min	0.875	19.23	18.41	66.3	11.22
	15 min	0.875	18.62	18.14	67.0	10.97
	20 min	0.872	18.84	18.57	66.2	10.93
	30 min	0.873	19.27	18.63	65.0	10.99

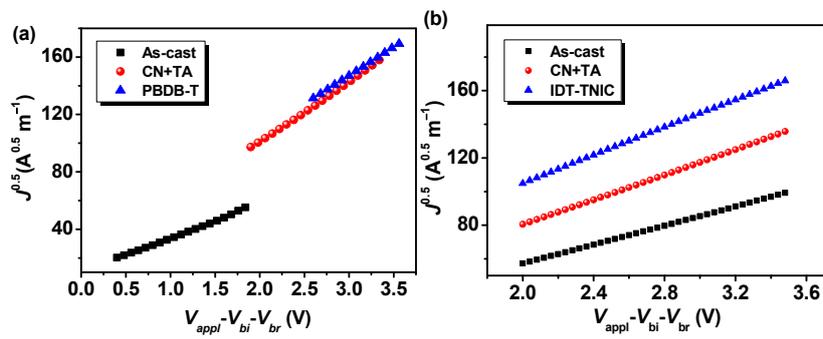


Figure S8. The $J^{0.5}$ - V plots for calculations of the hole-only (a) and electron-only (b) mobilities of PBDB-T:IDT-TNIC-based devices.

Table S7. Hole and electron mobilities of PBDB-T:IDT-TNIC-based devices measured by the SCLC method.

Materials	Conditions	μ_h (cm ⁻² V ⁻¹ s ⁻¹)	μ_e (cm ⁻² V ⁻¹ s ⁻¹)	μ_h/μ_e
PBDB-T	Pure film	3.91×10^{-4}	--	--
IDT-TNIC	Pure film	--	2.36×10^{-4}	--
PBDB-T:IDT-TNIC	As-cast	2.30×10^{-4}	1.73×10^{-4}	1.33
PBDB-T:IDT-TNIC	CN+TA	3.63×10^{-4}	3.19×10^{-4}	1.14
IDT-N [2]	Pure film	--	1.09×10^{-4}	--
PBDB-T:IDT-N [2]	CN+TA	4.57×10^{-4}	2.87×10^{-4}	1.59

IDT-TNIC	0.31	0.15	37.68	20.26	1.78	0.25	22.61	3.53
PBDB-T: IDT-TNIC	0.30	0.04	141.3	20.93	1.77	0.26	21.74	3.55

Reference

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